NSN 5961-01-291-5547

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-291-5547 **Inclosure Material:** Metal and glass **Overall Length:** Between 3.602 inches and 3.640 inches **Overall Height:** Between 1.120 inches and 1.170 inches Overall Width: Between 0.795 inches and 0.805 inches **End Application:** 2350-01-277-5770 **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 300.0 nonrepetitive peak reverse voltage all semiconductor device diode and 400.0 repetitive peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 80.00 amperes forward current, average all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 screw Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: